CeF₃: Tb³⁺/SiO₂ (core/shell) nanostructure : surface coating and photoluminescence

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CeF₃: Tb³⁺/SiO₂ (Core/Shell) with nanostructure were prepared by a complex method based on the surface modification of CeF₃: Tb³⁺ nanoparticles, which crystallized well with a hexagonal structure. The mean grain size of CeF₃: Tb³⁺ and CeF₃: Tb³⁺/SiO₂ are 10 nm and 14 nm, respectively. Both of them showed green emission corresponded ${}^{5}D_{4} - {}^{7}F_{J}$ transition of Tb³⁺, and especially the silica film increased the luminescent intensity and lifetimes of CeF₃: Tb³⁺ nanoparticles.

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1. Introduction

In recent years, growing efforts have been put into the luminescent materials with nanostructure, which present a broad range of potential applications, such as photoluminescent devices, biological fluorescence labeling, low-threshold lasers, optical amplifiers, and so on [1-7]. For example, Ma et al. [8] combined successfully the useful functions of super para-magnetism, luminescence, and surface functionality into one material with nano-architecture by sol-gel method. Valérie Buissette and his co-workers synthesized the nanoparticles constituted of a (Y, Ln)VO₄ crystalline core and stabilized by a lanthanide-citrate complex shell [9]. The construction of complex structure was not only a useful method to develop multi-functional materials but also an effective way to improve the luminescent properties. In the fields of traditional fluorescent materials the strategy to grow a suitable inorganic film around each phosphor particles to form the core/shell structures has been applied as an effective path to increase luminescent efficiency and stability. It was pointed out in earlier study that the luminescence efficiency of nanometer materials was usually lower than that of corresponding bulk materials because of nonradiative decay from defects on the surface of the nanocrystals [10, 11]. Recently that strategy also has been successfully applied in nanometer material systems. For instance, nanocomposite thin films where ZnGa₂O₄ nanoparticles were dispersed in fluorides, MgF2 or LaF3, were prepared by Hirokinaito et al. [12]. They found that enchantment of the PL emission of the composite films was due to the quantum size effect and the surfaces effects.

A bulk crystal of CeF₃ possesses a hexagonal phase structure with a space group of P3hc1 (D3d 4) and lattice constants *a*) 0.713 nm, *c*) 0.729 nm, and there are six

molecules in the unit cell. The Ce^{3+} ion in the CeF_3 crystal is coordinated by nine F^- and has a C_2 site symmetry. Because of the weaker diffuseness of their electron cloud, and broader energy gap, and low vibrational energies, which lead to the minimization of the quenching of the excited state of the rare-earth ions, lanthanide fluorides are useful luminescent host materials. As a potential scintillator and tunable laser material, CeF₃ is a luminescent material with 100 % activator concentration. Therefore nanometer CeF₃ crystal was often used to study the luminescent properties. Some works about the synthesis of luminescent and optical materials based on CeF₃ nanostructure material were published. S Eiden-Assmann and G. Maret [13] reported a polyol method to synthesize CeF_3 particles 5 – 10 nm in size. They also claimed that this material had a potential application in novel functional film with tunable magneto-optical properties. Liu et al. [14] presented the synthesis of monodispersive CeF₃ nanoparticles with different size from polyisobutene-butanediimede (T154) /cyclohexaner/water microemulsions. However in this case there was little work to grow SiO₂ films around CeF₃ nanoparticles. This paper totally concerned the synthesis and the fluorescent and thermal properties of CeF3 nanometer crystal coated SiO₂, which form CeF₃: Tb³⁺/SiO₂ (Core/Shell) nanostructure and result in luminescence enhancement though the surface modification.

2. Experimental

Synthesis. A complex process was adopted to prepare CeF_3 : Tb^{3+}/SiO_2 (core/shell) nanostructure based on the preparation of CeF_3 : Tb^{3+} nanoparticles by a glycol method [15]. La_2O_3 (99.99 %, Sinopharm Group Chemical

Reagent Co., Ltd. China), Tb_4O_7 (99.99 %, Sinopharm Group Chemical Reagent Co., Ltd.), $Ce(NO_3)_3 \cdot 6H_2O$ (99.99 %, Sinopharm Group Chemical Reagent Co., Ltd. China), NH_4F (99.0 %, analytical reagent, A. R., Sinopharm Group Chemical Reagent Co., Ltd. China), and TEOS([Si(C₂H₅O)₄] 99.0 %, Sinopharm Group Chemical Reagent Co., Ltd. China) were used as starting materials without any further purification. La(NO₃)₃ and Tb(NO₃)₃ were prepared by dissolving the corresponding oxides in diluted nitric acid, and the water in the solutions was distilled off by heating carefully.

CeF₃: Tb³⁺ nanoparticles. The doping concentration of Tb³⁺ in CeF₃ host was 10 mol %. Stoichiometric amounts of Ce(NO₃)₃ and Tb(NO₃)₃ (totally 2.0 mmol) were dissolved in 25 mL of DEG at 90 °C under stirring to form a clear solution. The solution was then heated in a silicon oil bath under vigorous stirring with a flow of Ar atmosphere, and the temperature of the solution was further increased to 200 °C. At this temperature, a solution of DEG (25 mL) containing 6 mmol of NH₄F was slowly injected into the above solution, and the mixture was kept at 200 °C for 1 h. Then, the obtained suspension was divided into two parts in volume uniformly. The one was cooled to room temperature and diluted with 25mL of The solid particles were separated ethanol. by centrifugation at a speed of 4500 rpm. To remove residual DEG, the solid powders were dispersed in ethanol and centrifuged again. The other one was used to prepare CeF₃: Tb³⁺/SiO₂ (core/shell) nanostructure

CeF₃: Tb³⁺/SiO₂ (Core/Shell) nanostructure. The CeF₃: Tb³⁺ / SiO₂ (core/shell) nanostructure was prepared by a further hydrolyzation process of TEOS around the obtained CeF₃: Tb³⁺ nanoparticles. Firstly, 50 mL of anhydrous ethanol and 2.0 mmol TEOS was added to the other one and heated to 120 °C for 1 hour with continuous stirring. Then 5 mL NH₄OH was added into the mixture by dropwise under continuous stirring in a silicon oil bath with a flow of Ar. And the suspension was kept at 160 °C for 0.5 h. The following procedures were same as those for the synthesis of CeF₃: Tb³⁺ nanoparticles as stated above.

Characterization. X-ray diffraction (XRD) was carried out on a Bruck D8-Advance diffractometer with CuK α radiation (0.15405 nm). The accelerating voltage and emission current were 40 kV and 40 mA, respectively. TEM images were obtained using a JEOL 1230 transmission electron microscope operating at 200 kV. Samples for TEM were prepared by depositing a drop of a colloidal ethanol solution of the powder sample onto a carbon coated copper grid. The excess liquid was wicked away with filter paper, and the grid was dried in air. Chemical analyses are performed by EDX using Philps XL-30 equipments. Fourier transform infrared (FTIR) spectra were measured within the 4000-400 cm⁻¹ region on an (Nicolet model 5SXC) infrared spectrophotometer with the KBr pellet technique. The excitation and emission spectra were taken on a RF-5301 spectrophotometer whose excitation and emission slits width were both 3 nm. All the emission and excitation spectra were corrected and the intensities were determined with integrated area. Luminescent lifetimes for hybrid materials were obtained with an Edinburgh Instruments FLS 920 phosphorimeter using a 450 W xenon lamp as excitation source (pulse width, 3μ s).

3. Results and discussion

3.1 Microstructure and Morphology of the Nanocrystals

We investigated the phase structures of the nanoparticles by X-ray powder diffraction. Fig. 1 gives XRD patterns of CeF₃: 10%Tb (a), and CeF₃: 10%Tb/SiO₂ core/shell (b) nanostructure. The reference lines for CeF₃ provided in the JCPDS database (No. 08-0045) are also displayed. Deduced from the XRD data, these two samples are well-crystallized, and both patterns are in good agreement with hexagonal phase structure known from the bulk CeF₃ crystal. This also suggests that the doped Tb^{3+} ions uniformly enter into CeF₃ crystal lattice to form homogeneous solid solution without hybrid phase to be found in XRD peaks. For our CeF₃: 10%Tb/SiO₂ core/shell system, no obvious distinction is observed for the diffraction peaks with respect to those of the CeF₃: 10%Tb core nanoparticles, (as shown in Figure 1), which indicate that SiO₂ does not crystallize well and exists as amorphous substance. Besides, all peaks broaden obviously owing to the small size of the particles. The crystallite sizes can be estimated from the Scherrer equation, $D = 0.941\lambda/\beta \cos\theta$, where D is the average grain size, λ is the X-ray wavelength (0.15405 nm), and θ and β are the diffraction angle and full-width at half-maximum (fwhm) of an observed peak, respectively. The strongest and independent peak (111) at $2\theta = 27.8$ ° was used to calculate the grain size of the materials.



Fig. 1 The XRD patterns of the samples.

3.2 Microstructure and Morphology

TEM were performed to observe the morphology of the obtained samples. And the micrographs are shown in Fig. 2. Fig. 2a gives the image of CeF₃: 10%Tb particles magnified 500,000 times. From the picture the size of CeF₃: 10%Tb particles is about 7-10 nm, and the shape is fairly regular, also agglomeration between the particles is slight. The image of CeF₃: 10%Tb/SiO₂ material was shown in Fig.2b. The results demonstrate that there is a little difference between the two samples: the particle size of CeF₃: 10%Tb/SiO₂ is bigger than that of CeF₃: 10%Tb, which does not take in good agreement with of XRD results (see in table 1). As we known that the size result caculated from Scherrer equation only gives the size of the CeF₃ single crystal, which is same in two samples. Therefore the calculated size of the particles of CeF₃: 10%Tb/SiO₂ is similar with that of CeF₃. But the real size of CeF₃: 10%Tb/SiO₂ particles, which contains CeF₃ crystallite and amorphous silica shell, is the sum of the size of CeF₃ and the double thickness of silica film. Based on the size analysis from Fig. 2b, the thickness of silica film is about 2 nm. The lattice fringes of crystalline CeF₃: 10% Tb can be seen more clearly than that of CeF_3 : 10%Tb/SiO₂. The reason that more interaction between the amorphous silica films lead to the agglomeration of particles is available.





Fig. 2 TEM micron morphologies of samples (A): CeF_3 : Tb^{3+} and (B): CeF_3 : Tb^{3+}/SiO_2 .

Size (nm)	CeF ₃ : 10%Tb	CeF ₃ :
	nanoparticles	10%Tb/SiO ₂
		nanostructure
XRD	8.5	8.0
TEM	10.0	14.0

It is well know that on the alkali conditions TEOS is easy to hydrolysis, so the formation of silica film include the hydrolysis process of TEOS and the polycondensation reaction of the hydroxyl derivatives to form Si-O network. The detailed scheme of the formation of core/shell nanostructure is shown in Fig. 3. To obtain information about the chemical composition of nanoparticles EDX measurements were performed. The EDX spectrum (Fig. 4) suggests that Si and O are only detected on the CeF₃: 10%Tb/SiO₂ sample, which conform that TEOS

hydrolyzed successfully.



Fig. 3 The scheme of the formation process of core/shell nanostructure.

Fig. 5(a, b) shows the FT-IR spectra of CeF₃: 10%Tb (a), and CeF₃: 10%Tb/SiO₂, respectively. It should be noted that some main absorption peaks observed at approximately 1591, 1508, 1385 cm⁻¹, can be attributed to the remanent organic solvent. There is distinct difference between the two spectra. And a strong and broad absorption band in CeF₃: 10%Tb/SiO₂ are observed at approximately 800 cm⁻¹, which is attributed to the antisymmetric stretching vibration of Si–O bonding of silica.

Table 1. the size of samples from XRD and TEM, respectively.



Fig. 4 Energy dispersive X-ray spectra of obtained samples (A): CeF_3 : Tb^{3+} and (B): CeF_3 : Tb^{3+}/SiO_2 .



Fig. 5 The FT-IR spectra of CeF₃: 10%Tb (a), and CeF₃: 10%Tb/SiO₂.



Fig. 6 The Excitation (A) and emission (B) spectra of CeF₃: 10%Tb and CeF₃: 10%Tb/SiO₂.

3.3 Luminescent properties

The luminescent spectra of trivalent lanthanide ions in phosphors are mainly from two types of electronic transitions: 4f - 4f transition and 5d - 4f transition. The former generally shows sharp emission line, while the latter have a broad band character. Fig. 6(A) is the room temperature excitation spectral of samples CeF₃: 10%Tb (a) and CeF₃: 10%Tb/SiO₂ (b). The excitation spectra were obtained by monitoring the ${}^{5}D_{4} - {}^{7}F_{5}$ transition of Tb³⁺ ions (543 nm). It can be clearly shown that the excitation spectra consist of two parts, one broadband in the 240-300 nm region resulted from the well-known ${}^{2}F_{5/2} - 5d$ (or 4f -5d) transition of Ce^{3+} and several sharp peaks in 320 - 500nm region related to the f-f transitions of Tb³⁺ ions. Fig. 6 (B) shows the emission spectra of the obtained sample which were measured under 310 nm excitation at the room temperature. The sharp emission peaks originates from the 4f - 4f transition of Tb^{3+} ions: ${}^{5}D_{4} - {}^{7}F_{6}$ (488 nm), ${}^{5}D_{4} - {}^{7}F_{6}$

 ${}^{7}F_{5}$ (541 nm) ${}^{5}D_{4} - {}^{7}F_{4}$ (583 nm) and very weak ${}^{5}D_{4} - {}^{7}F_{4}$ (433 nm). ${}^{5}D_{4} - {}^{7}F_{5}$ (413 nm). In addition, the spectra of two samples both suggest that silica film can increase the luminescent intensities, which may be caused by the coated silica film. Furtherly, the luminescent lifetimes for CeF₃: 10%Tb (a) and CeF₃: 10%Tb/SiO₂ are 0.74 ms and 0.97 ms, suggest the surface coating can effectively decrease the nonradiative transition. Although the quantum efficiency of Tb system is too complicated to be calculated from the lifetime data, we still predict that the quantum efficiency for CeF₃: 10%Tb/SiO₂ may be higher than CeF₃: 10%Tb because it possess longer lifetime [16-18].

4. Conclusion

CeF₃: Tb³⁺/SiO₂ (Core/Shell) summary, In nanostructure luminescent materials were successfully prepared by a complex method based on preparation of CeF₃: Tb³⁺ nanoparticles. XRD measurement indicated that the obtained CeF₃: Tb³⁺, and CeF₃: Tb³⁺/SiO₂ (Core/Shell) nanometer materials crystallized well. And the amorphous silica shell had not influence on the lattice parameters of CeF₃: Tb^{3+} . FI-IR spectra and EDX results suggest the existence of SiO₂ on the surface of the particles. The TEM images illustrated that the mean grain size of CeF₃: Tb³⁺ and CeF₃: Tb³⁺/SiO₂ are 10 nm and 14 nm, respectively. Under 254nm UV lamp CeF₃: Tb³⁺and CeF₃: Tb³⁺/SiO₂ both showed green emission, and fluorescent experiments revealed that the both nanometer materials showed the characteristic emission of Tb^{3+ 5}D₄ $-{}^{7}F_{I}$ (J = 6, 5, 4, 3) transition, with the strongest one at 542 nm. The luminescent properties also revealed that the silica film increased the luminescent intensity and lifetimes of CeF₃: Tb³⁺ nanoparticles.

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References

- J. S. Steckel, J. P. Zimmer, S. Coe-Sullivan, Angew. Chem. Int. Ed. 43, 2154 (2004).
- [2] Z. W. Quan, Z. L. Wang, P. P. Yang, Inorg. Chem. ASAP (2007).
- [3] V. Salgueiriño-Maceira, M. A. Correa-Duarte, M. Spasova, Adv. Funct. Mater. 16 (2006) 509.
- [4] A. Mayer, S. Neuenhofer, Angew. Chem. Int. Ed. 33, 1044 (1994).
- [5] J. W. Gerald, A. Hebbink, J. Huskens, Chem. Mater. 15, 4604 (2003).
- [6] W. Tan, K. Wang, X. He, Med. Res. Rev. 24, 621 (2004).
- [7] V. Buissette, M. Moreau, T. Gacoin, Adv. Funct. Mater. 16, 351 (2006).
- [8] D. Ma, J. Guan, F. Normadin, Chem. Mater. 18, 1920 (2006).
- [9] V. Buissette, A. Huignarda, K. Lahlila, Proc. of SPIE 5222, 141 (2003).
- [10] W. Bu, Z. Hua, H. Chen, J. Shi, J. Phys. Chem. B 109, 14461 (2005).
- [11] Q. Li, L. Gao, D. Yan, Chem. Mater. 11, 533 (1999).
- [12] H. Naito, S. Fujihara, T. Kimura, J. Sol-Gel Sci. Technol. 26, 997 (2003).
- [13] S. Eiden-Assmann, G. Maret, Mater. Res. Bull. 39, 21 (2004).
- [14] S. Q. Qiu, J. X. Dong, G. X. Chen, Powder Technol. 113, 9 (2000).
- [15] Z. L. Wang, Z. W. Quan, P. Y. Jia, Chem. Mater. 18, 2030 (2006).
- [16] M. H. V. Werts, R. T. F. Jukes, J. W. Verhoeven, Phys. Chem. Chem. Phys. 4, 1542 (2002).
- [17] O. L. Malta, M. A. Couto dos Santos,L. C. Thompson, N. K. Ito, J. Lumin. 69, 77 (1996).
- [18] O. L. Malta, H. F.Brito, J. F. S. Menezes,
 F. R. Gonc, alves e Silva, Alves, F. S. Farias,
 A. V. M. Andrade, J. Lumin. 75, 255 (1997).

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